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March 2007

Controlling Interface Properties for Advanced Energy Applications

Rui Shao
University of Pennsylvania

D. Li
University of Pennsylvania

Ramsay A. Kraya
University of Pennsylvania

Dawn A. Bonnell
University of Pennsylvania, BONNELL@SEAS.UPENN.EDU

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Shao, Rui; Li, D.; Kraya, Ramsay A.; and Bonnell, Dawn A., "Controlling Interface Properties for Advanced Energy Applications" (2007). *Energy Research Group Posters*. 4.
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Poster presented at *The Search for a Sustainable Energy Future: Challenges for Basic Research*, A Mini-Symposium sponsored by the Energy Working Group at Penn, March 9, 2007.

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Controlling Interface Properties for Advanced Energy Applications

Abstract

Internal interfaces in materials play an important role in the performance of many devices used in energy applications including solar cells, LEDs, passive electronics, and fuel cells. Efficiencies in energy and power consumption may be realized by optimizing and often miniaturizing these devices. Our studies show that internal boundaries and biomaterial interfaces cause local property variations. These effects will dominate device performance as the systems become smaller. A fundamental understanding of the effect of atomic structure on local properties is a prerequisite to device optimization. Developing this understanding requires new probes that access local properties, controlled interface structure, atomic resolution electron microscopy and first principles calculations of geometric and electronic structure.

Comments

Poster presented at *The Search for a Sustainable Energy Future: Challenges for Basic Research*, A Mini-Symposium sponsored by the Energy Working Group at Penn, March 9, 2007.

Controlling Interface Properties for Advanced Energy Applications

R. Shao, D. Li, R. Kraya, D. Bonnell, Department of Materials Science

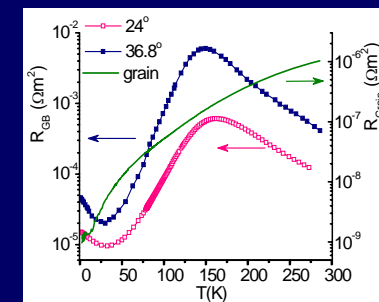
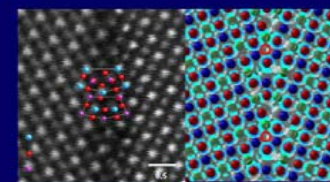
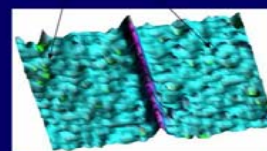
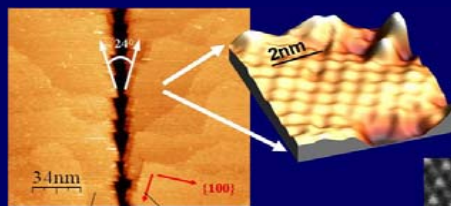


Introduction

Internal interfaces in materials play an important role in the performance of many devices used in energy applications including solar cells, LEDs, passive electronics, and fuel cells. Efficiencies in energy and power consumption may be realized by optimizing and often miniaturizing these devices. Our studies show that internal boundaries and biomaterial interfaces cause local property variations. These effects will dominate device performance as the systems become smaller. A fundamental understanding of the effect of atomic structure on local properties is a prerequisite to device optimization. Developing this understanding requires new probes that access local properties, controlled interface structure, atomic resolution electron microscopy and first principles calculations of geometric and electronic structure.

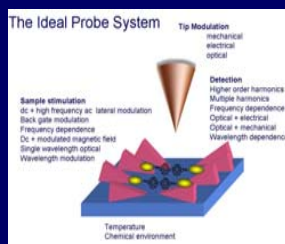
Structure and Properties of Internal Interfaces

The charge at SrTiO₃ grain boundaries is due to periodic under coordinated Ti in the boundary so the amount at any boundary depends on the atomic structure, i.e. there is one electron associated with each Ti polyhedron. This interface charge causes local dielectric constant suppression adjacent to the interface. In addition the charge induces ferroelectric dipole formation and alignment at a mid temperature phase transition in SrTiO₃.



New Probes of Local Properties

The two new multiple modulation techniques, developed at Penn, have been shown to successfully overcome barriers to quantifying local electrical behavior.



Direct imaging of charge at a SrTiO₃ bicrystal boundary by SSPM

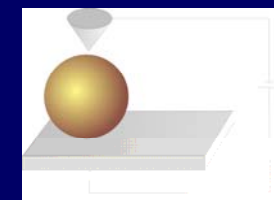
Aberration corrected Z-contrast TEM image of a SrTiO₃ bicrystal grain boundary

Calculated charge density distribution at the grain boundary

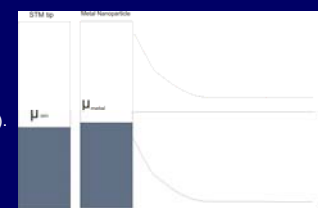
Extension to Interfaces of Nanocontacts

Characterizing the properties of a metal-semiconductor nano-contact is crucial to the emergence of nano-electronic devices. We have shown that contact potential can be size dependent. Discovering the mode of conduction through the contact and the effects of surface states on the interface barrier are two of the most important aspects of understanding the nature of the contact. By combining SIM with STM and spectroscopy, the fundamental properties governing the interaction of metals and semiconductors can be determined.

A metal nanoparticle on a semiconductor substrate.

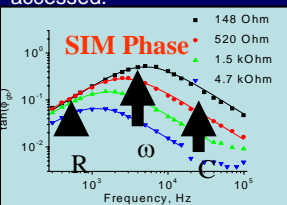


Band-level diagram of a 2-step electron transfer process. In this diagram electrons flow from the semiconductor to the metal nanoparticle and finally to the tip.



Scanning Impedance Microscopy SIM

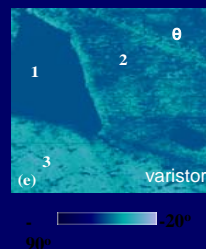
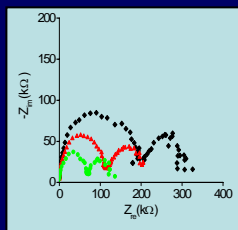
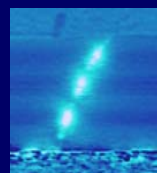
The modulating electric signal is applied laterally across the surface rather than to the tip, allowing R, C, and trap state time constants to be accessed.



Nanoimpedance Microscopy NIM

Monitoring the frequency dependence over 6 orders of magnitude yields the real and imaginary contributions to impedance.

Defects in a Carbon Nanotube



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